



Welcome to E-XFL.COM

What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	180MHz
Connectivity	CANbus, EBI/EMI, I²C, IrDA, Microwire, SD, SPI, SSI, SSP, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I²S, POR, WDT
Number of I/O	49
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	16K x 8
RAM Size	136K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 3.6V
Data Converters	A/D 4x10b; D/A 1x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-TFBGA
Supplier Device Package	100-TFBGA (9x9)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/lpc1817jet100e

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
P1_8	R7	H5	51	71	[2]	N; PU	I/O	GPIO1[1] — General purpose digital input/output pin.
							O	U1_DTR — Data Terminal Ready output for UART1.
							O	CTOUT_12 — SCTimer/PWM output 12. Match output 3 of timer 3.
							I/O	EMC_D1 — External memory data line 1.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							O	SD_VOLT0 — SD/MMC bus voltage select output 0.
P1_9	T7	J5	52	73	[2]	N; PU	I/O	GPIO1[2] — General purpose digital input/output pin.
							O	U1 RTS — Request to Send output for UART1.
							O	CTOUT_11 — SCTimer/PWM output 11. Match output 3 of timer 2.
							I/O	EMC_D2 — External memory data line 2.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							I/O	SD_DAT0 — SD/MMC data bus line 0.
P1_10	R8	H6	53	75	[2]	N; PU	I/O	GPIO1[3] — General purpose digital input/output pin.
							I	U1_RI — Ring Indicator input for UART1.
							O	CTOUT_14 — SCTimer/PWM output 14. Match output 2 of timer 3.
							I/O	EMC_D3 — External memory data line 3.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							I/O	SD_DAT1 — SD/MMC data bus line 1.
P1_11	T9	J7	55	77	[2]	N; PU	I/O	GPIO1[4] — General purpose digital input/output pin.
							I	U1_CTS — Clear to Send input for UART1.
							O	CTOUT_15 — SCTimer/PWM output 15. Match output 3 of timer 3.
							I/O	EMC_D4 — External memory data line 4.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							I/O	SD_DAT2 — SD/MMC data bus line 2.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
P4_3	C2	-	7	10	[5]	N; PU	I/O	GPIO2[3] — General purpose digital input/output pin.
							O	CTOUT_3 — SCTimer/PWM output 3. Match output 3 of timer 0.
							O	LCD_VD2 — LCD data.
							-	R — Function reserved.
							-	R — Function reserved.
							O	LCD_VD21 — LCD data.
							I/O	U3_BAUD — Baud pin for USART3.
							-	R — Function reserved.
P4_4	B1	-	9	14	[5]	N; PU	I/O	GPIO2[4] — General purpose digital input/output pin.
							O	CTOUT_2 — SCTimer/PWM output 2. Match output 2 of timer 0.
							O	LCD_VD1 — LCD data.
							-	R — Function reserved.
							-	R — Function reserved.
							O	LCD_VD20 — LCD data.
							I/O	U3_DIR — RS-485/EIA-485 output enable/direction control for USART3.
							-	R — Function reserved.
P4_5	D2	-	10	15	[2]	N; PU	I/O	GPIO2[5] — General purpose digital input/output pin.
							O	CTOUT_5 — SCTimer/PWM output 5. Match output 3 of timer 3.
							O	LCD_FP — Frame pulse (STN). Vertical synchronization pulse (TFT).
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.

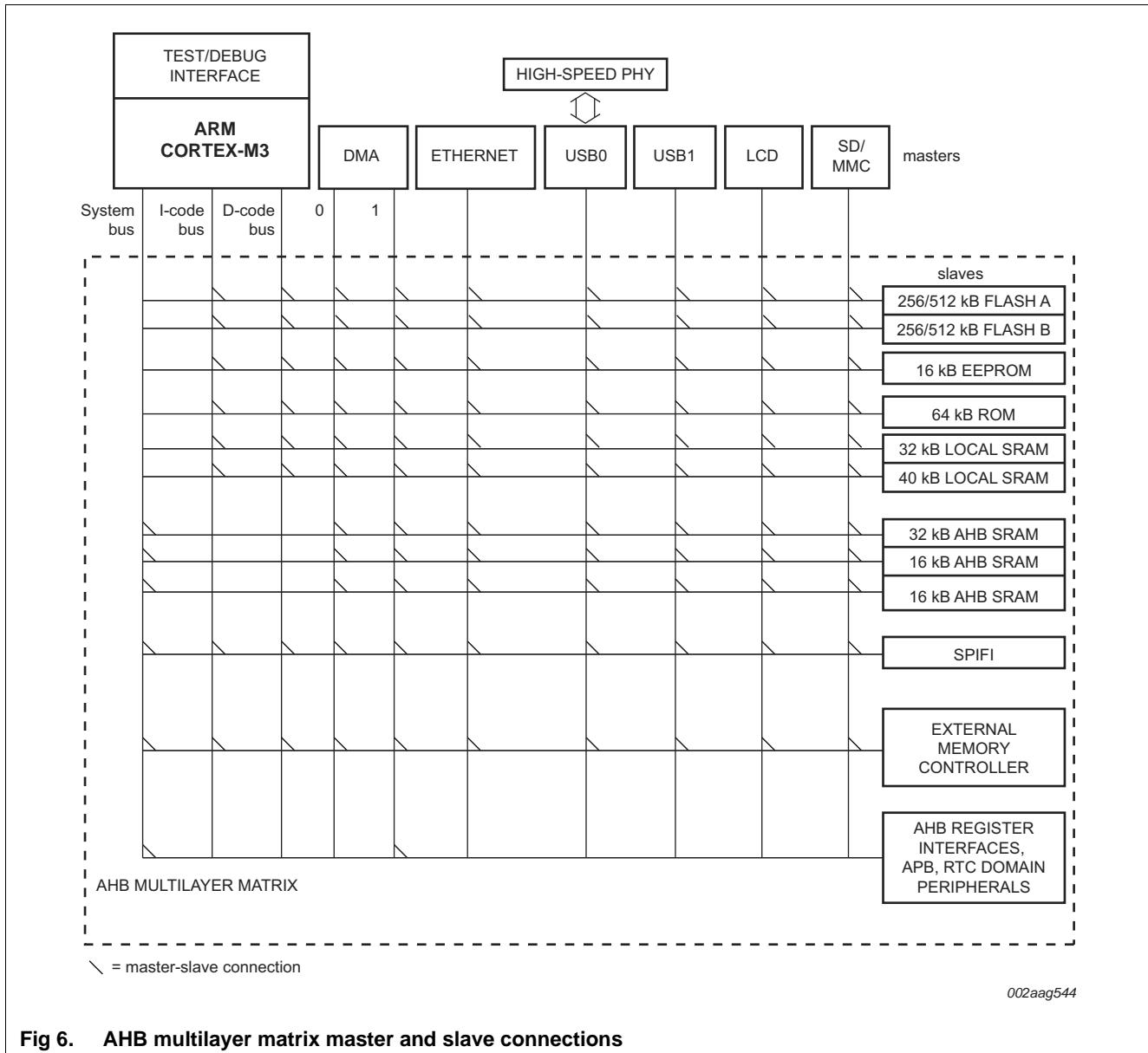
Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
PC_7	G5	-	-	-	[2]	N; PU	-	R — Function reserved.
							I/O	USB1_ULPI_D1 — ULPI link bidirectional data line 1.
							-	R — Function reserved.
							I	ENET_RXD3 — Ethernet receive data 3 (MII interface).
							I/O	GPIO6[6] — General purpose digital input/output pin.
							-	R — Function reserved.
							O	T3_MAT0 — Match output 0 of timer 3.
							I/O	SD_DAT3 — SD/MMC data bus line 3.
PC_8	N4	-	-	-	[2]	N; PU	-	R — Function reserved.
							I/O	USB1_ULPI_D0 — ULPI link bidirectional data line 0.
							-	R — Function reserved.
							I	ENET_RX_DV — Ethernet Receive Data Valid (RMII/MII interface).
							I/O	GPIO6[7] — General purpose digital input/output pin.
							-	R — Function reserved.
							O	T3_MAT1 — Match output 1 of timer 3.
							I	SD_CD — SD/MMC card detect input.
PC_9	K2	-	-	-	[2]	N; PU	-	R — Function reserved.
							I	USB1_ULPI_NXT — ULPI link NXT signal. Data flow control signal from the PHY.
							-	R — Function reserved.
							I	ENET_RX_ER — Ethernet receive error (MII interface).
							I/O	GPIO6[8] — General purpose digital input/output pin.
							-	R — Function reserved.
							O	T3_MAT2 — Match output 2 of timer 3.
							O	SD_POW — SD/MMC power monitor output.
PC_10	M5	-	-	-	[2]	N; PU	-	R — Function reserved.
							O	USB1_ULPI_STP — ULPI link STP signal. Asserted to end or interrupt transfers to the PHY.
							I	U1_DSR — Data Set Ready input for UART1.
							-	R — Function reserved.
							I/O	GPIO6[9] — General purpose digital input/output pin.
							-	R — Function reserved.
							O	T3_MAT3 — Match output 3 of timer 3.
							I/O	SD_CMD — SD/MMC command signal.

Table 3. Pin description ...continued

Pin name	LBGA256	TFBGA100	LQFP144	LQFP208		Reset state [1]	Type	Description
PE_3	K12	-	-	118	[2]	N; PU	-	R — Function reserved.
							O	CAN0_TD — CAN transmitter output.
							I	ADCTRIG1 — ADC trigger input 1.
							I/O	EMC_A21 — External memory address line 21.
							I/O	GPIO7[3] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
PE_4	K13	-	-	120	[2]	N; PU	-	R — Function reserved.
							I	NMI — External interrupt input to NMI.
							-	R — Function reserved.
							I/O	EMC_A22 — External memory address line 22.
							I/O	GPIO7[4] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
PE_5	N16	-	-	122	[2]	N; PU	-	R — Function reserved.
							O	CTOUT_3 — SCTimer/PWM output 3. Match output 3 of timer 0.
							O	U1_RTS — Request to Send output for UART1. Can also be configured to be an RS-485/EIA-485 output enable signal for UART1.
							I/O	EMC_D24 — External memory data line 24.
							I/O	GPIO7[5] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.
PE_6	M16	-	-	124	[2]	N; PU	-	R — Function reserved.
							O	CTOUT_2 — SCTimer/PWM output 2. Match output 2 of timer 0.
							I	U1_RI — Ring Indicator input for UART1.
							I/O	EMC_D25 — External memory data line 25.
							I/O	GPIO7[6] — General purpose digital input/output pin.
							-	R — Function reserved.
							-	R — Function reserved.
							-	R — Function reserved.

7.4 AHB multilayer matrix



7.5 Nested Vectored Interrupt Controller (NVIC)

The NVIC is part of the Cortex-M3. The tight coupling to the CPU allows for low interrupt latency and efficient processing of late arriving interrupts.

7.5.1 Features

- Controls system exceptions and peripheral interrupts.
- On the LPC185x/3x/2x/1x, the NVIC supports 53 vectored interrupts.
- Eight programmable interrupt priority levels, with hardware priority level masking.
- Relocatable vector table.

7.9 On-chip flash memory

The LPC185x/3x/2x/1x contain up to 1 MB of dual-bank flash program memory. With dual-bank flash memory, the user code can write or erase one flash bank while reading the other flash bank without interruption. A two-port flash accelerator maximizes the flash performance.

In-System Programming (ISP) and In-Application Programming (IAP) routines for programming the flash memory are provided in the Boot ROM.

7.10 EEPROM

The LPC185x/3x/2x/1x contain up to 16 kB of on-chip byte-erasable and byte-programmable EEPROM memory.

The EEPROM memory is divided into 128 pages. The user can access pages 1 through 127. Page 128 is protected.

7.11 Boot ROM

The internal ROM memory is used to store the boot code of the LPC185x/3x/2x/1x. After a reset, the ARM processor will start its code execution from this memory.

The boot ROM memory includes the following features:

- The ROM memory size is 64 kB.
- Supports booting from external static memory such as NOR flash, SPI flash, quad SPI flash, USB0, and USB1.
- Includes API for OTP programming.
- Includes a flexible USB device stack that supports Human Interface Device (HID), Mass Storage Class (MSC), and Device Firmware Upgrade (DFU) drivers.

The default boot source is the flash memory. Several other boot modes are available if P2_7 is LOW on reset depending on the values of the OTP bits BOOT_SRC. If the OTP memory is not programmed or the BOOT_SRC bits are all zero, the states of the boot pins P2_9, P2_8, P1_2, and P1_1 determine the boot mode.

Table 4. Boot mode when OTP BOOT_SRC bits are programmed

Boot mode	BOOT_SRC bit 3	BOOT_SRC bit 2	BOOT_SRC bit 1	BOOT_SRC bit 0	Description
Pin state	0	0	0	0	The reset state of P1_1, P1_2, P2_8, and P2_9 pins determines the boot source. See Table 5 .
USART0	0	0	0	1	Enter ISP mode using USART0 functions on pins P2_0 and P2_1.
SPIFI	0	0	1	0	Boot from Quad SPI flash connected to the SPIFI interface using pins P3_3 to P3_8.
EMC 8-bit	0	0	1	1	Boot from external static memory (such as NOR flash) using CS0 and an 8-bit data bus.
EMC 16-bit	0	1	0	0	Boot from external static memory (such as NOR flash) using CS0 and a 16-bit data bus.
EMC 32-bit	0	1	0	1	Boot from external static memory (such as NOR flash) using CS0 and a 32-bit data bus.

Table 4. Boot mode when OTP BOOT_SRC bits are programmed

Boot mode	BOOT_SRC bit 3	BOOT_SRC bit 2	BOOT_SRC bit 1	BOOT_SRC bit 0	Description
USB0	0	1	1	0	Boot from USB0.
USB1	0	1	1	1	Boot from USB1.
SPI (SSP)	1	0	0	0	Boot from SPI flash connected to the SSP0 interface on P3_3 (function SSP0_SCK), P3_6 (function SSP0_SSEL), P3_7 (function SSP0_MISO), and P3_8 (function SSP0_MOSI) ^[1] .
USART3	1	0	0	1	Enter ISP mode using USART3 functions on pins P2_3 and P2_4.

[1] The boot loader programs the appropriate pin function at reset to boot using either SSP0 or SPIFI.

Remark: Pin functions for SPIFI and SSP0 boot are different.

Table 5. Boot mode when OPT BOOT_SRC bits are zero

Boot mode	Pins				Description
	P2_9	P2_8	P1_2	P1_1	
USART0	LOW	LOW	LOW	LOW	Enter ISP mode using USART0 pins P2_0 and P2_1.
SPIFI	LOW	LOW	LOW	HIGH	Boot from Quad SPI flash connected to the SPIFI interface on P3_3 to P3_8 ^[1] .
EMC 8-bit	LOW	LOW	HIGH	LOW	Boot from external static memory (such as NOR flash) using CS0 and an 8-bit data bus.
EMC 16-bit	LOW	LOW	HIGH	HIGH	Boot from external static memory (such as NOR flash) using CS0 and a 16-bit data bus.
EMC 32-bit	LOW	HIGH	LOW	LOW	Boot from external static memory (such as NOR flash) using CS0 and a 32-bit data bus.
USB0	LOW	HIGH	LOW	HIGH	Boot from USB0
USB1	LOW	HIGH	HIGH	LOW	Boot from USB1.
SPI (SSP)	LOW	HIGH	HIGH	HIGH	Boot from SPI flash connected to the SSP0 interface on P3_3 (function SSP0_SCK), P3_6 (function SSP0_SSEL), P3_7 (function SSP0_MISO), and P3_8 (function SSP0_MOSI) ^[1] .
USART3	HIGH	LOW	LOW	LOW	Enter ISP mode using USART3 pins P2_3 and P2_4.

[1] The boot loader programs the appropriate pin function at reset to boot using either SSP0 or SPIFI.

Remark: Pin functions for SPIFI and SSP0 boot are different.

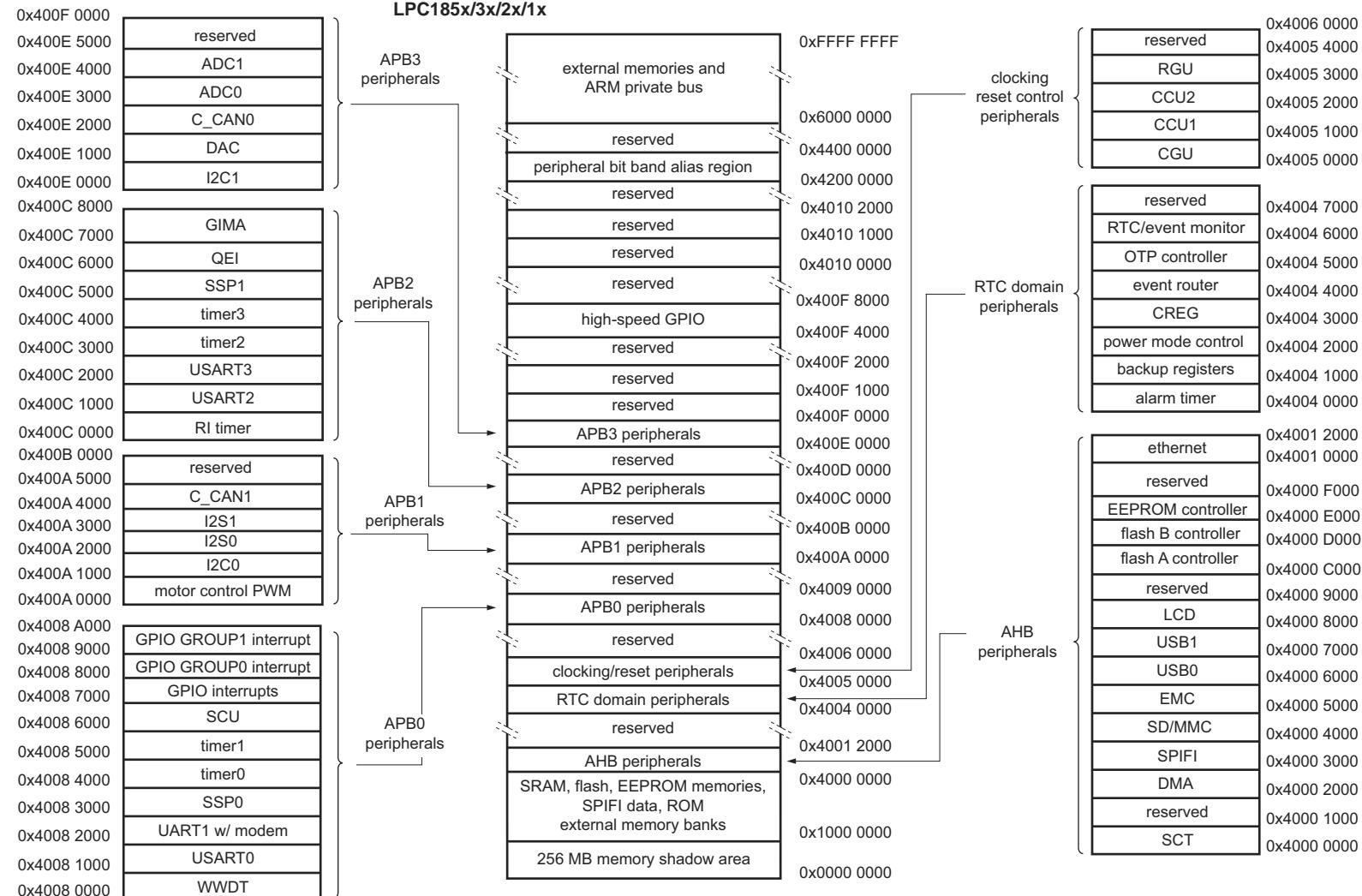


Fig 8. LPC185x/3x/2x/1x Memory mapping (peripherals)

- 15 gray-level monochrome, 3375 color STN, and 32 K color palettized TFT support.
- 1, 2, or 4 bits-per-pixel (bpp) palettized displays for monochrome STN.
- 1, 2, 4, or 8 bpp palettized color displays for color STN and TFT.
- 16 bpp true-color non-palettized for color STN and TFT.
- 24 bpp true-color non-palettized for color TFT.
- Programmable timing for different display panels.
- 256 entry, 16-bit palette RAM, arranged as a 128×32 -bit RAM.
- Frame, line, and pixel clock signals.
- AC bias signal for STN, data enable signal for TFT panels.
- Supports little and big-endian, and Windows CE data formats.
- LCD panel clock can be generated from the peripheral clock, or from a clock input pin.

7.15.9 Ethernet

Remark: The ethernet controller is available on parts LPC185x and LPC183x. Ethernet is not available on parts LPC182x and LPC181x.

7.15.9.1 Features

- 10/100 Mbit/s.
- DMA support.
- Power management remote wake-up frame and magic packet detection.
- Supports both full-duplex and half-duplex operation
 - Supports CSMA/CD Protocol for half-duplex operation.
 - Supports IEEE 802.3x flow control for full-duplex operation.
 - Optional forwarding of received pause control frames to the user application in full-duplex operation.
 - Back-pressure support for half-duplex operation.
 - Automatic transmission of zero-quanta pause frame on deassertion of flow control input in full-duplex operation.
- Support for IEEE 1588 time stamping and IEEE 1588 advanced time stamping (IEEE 1588-2008 v2).

7.16 Digital serial peripherals

7.16.1 UART

Remark: The LPC185x/3x/2x/1x contain one UART with standard transmit and receive data lines.

UART1 also provides a full modem control handshake interface and support for RS-485/9-bit mode allowing both software address detection and automatic address detection using 9-bit mode.

UART1 includes a fractional baud rate generator. Standard baud rates such as 115200 Bd can be achieved with any crystal frequency above 2 MHz.

7.16.1.1 Features

- Maximum UART data bit rate of 8 MBit/s.
- 16 B Receive and Transmit FIFOs.
- Register locations conform to 16C550 industry standard.
- Receiver FIFO trigger points at 1 B, 4 B, 8 B, and 14 B.
- Built-in fractional baud rate generator covering wide range of baud rates without a need for external crystals of particular values.
- Auto baud capabilities and FIFO control mechanism that enables software flow control implementation.
- Equipped with standard modem interface signals. This module also provides full support for hardware flow control (auto-CTS/RTS).
- Support for RS-485/9-bit/EIA-485 mode (UART1).
- DMA support.

7.16.2 USART

Remark: The LPC185x/3x/2x/1x contain three USARTs. In addition to standard transmit and receive data lines, the USARTs support a synchronous mode and a smart card mode.

The USARTs include a fractional baud rate generator. Standard baud rates such as 115200 Bd can be achieved with any crystal frequency above 2 MHz.

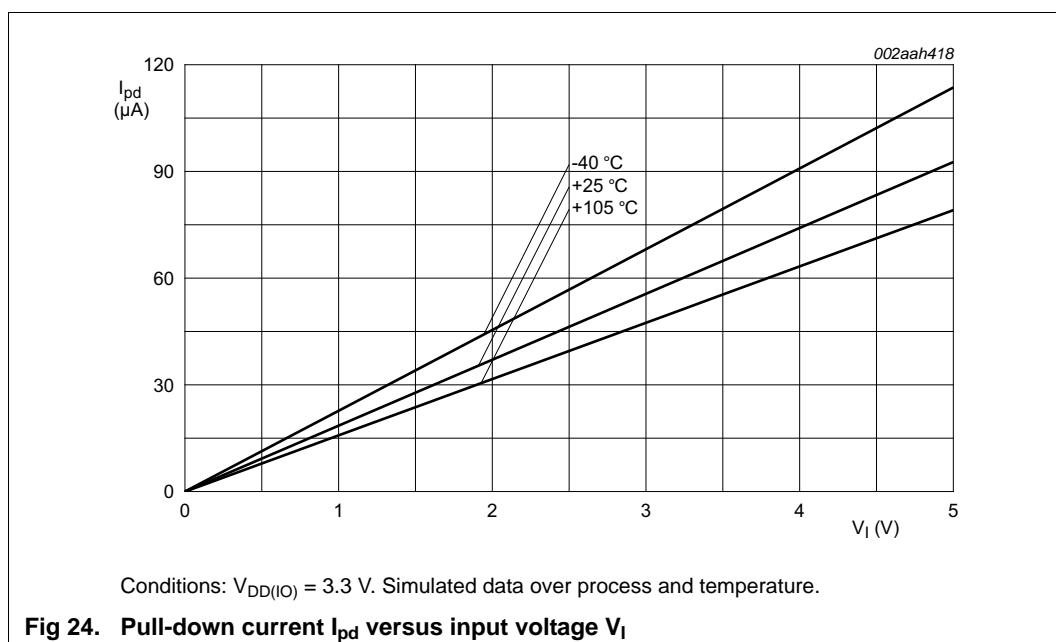
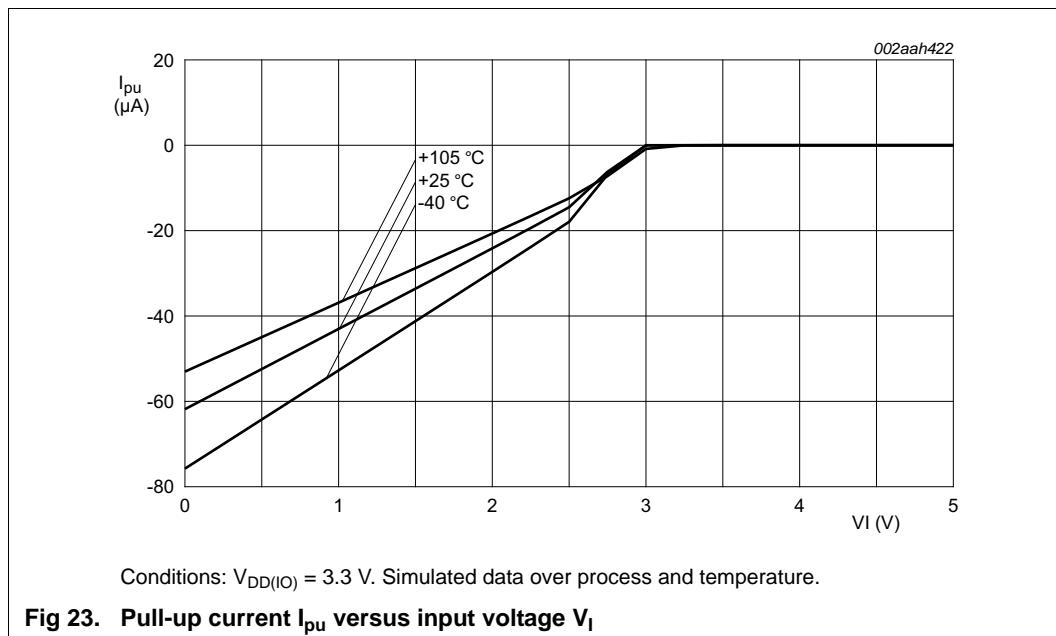
7.16.2.1 Features

- Maximum UART data bit rate of 8 MBit/s.
- 16 B Receive and Transmit FIFOs.
- Register locations conform to 16C550 industry standard.
- Receiver FIFO trigger points at 1 B, 4 B, 8 B, and 14 B.
- Built-in fractional baud rate generator covering wide range of baud rates without a need for external crystals of particular values.
- Auto baud capabilities and FIFO control mechanism that enables software flow control implementation.
- Support for RS-485/9-bit/EIA-485 mode.
- USART3 includes an IrDA mode to support infrared communication.
- All USARTs have DMA support.
- Support for synchronous mode at a data bit rate of up to 8 Mbit/s.
- Smart card mode conforming to ISO7816 specification

7.16.3 SSP serial I/O controller

Remark: The LPC185x/3x/2x/1x contain two SSP controllers.

The SSP controller can operate on a SPI, 4-wire SSI, or Microwire bus. It can interact with multiple masters and slaves on the bus. Only a single master and a single slave can communicate on the bus during a given data transfer. The SSP supports full-duplex



10.4 BOD and band gap static characteristics

Table 13. BOD static characteristics^[1]*T_{amb} = 25 °C; simulated values for nominal processing.*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V _{th}	threshold voltage	interrupt level 2				
		assertion	-	2.95	-	V
		de-assertion	-	3.03	-	V
		interrupt level 3				
		assertion	-	3.05	-	V
		de-assertion	-	3.13	-	V
		reset level 2				
		assertion	-	2.1	-	V
		de-assertion	-	2.18	-	V
		reset level 3				
		assertion	-	2.2	-	V
		de-assertion	-	2.28	-	V

[1] Interrupt and reset levels are selected by writing to the BODLV1/2 bits in the control register CREGE0, see the *LPC18xx user manual*.

Table 14. Band gap characteristics*V_{DDA(3V3)} over specified ranges; T_{amb} = -40 °C to +105 °C; unless otherwise specified*

Symbol	Parameter	Min	Typ	Max	Unit
V _{ref(bg)}	band gap reference voltage	[1] 0.707	0.745	0.783	mV

[1] Based on characterization, not tested in production.

Table 29. Dynamic characteristics: Dynamic external memory interface

Simulated data over temperature and process range; $C_L = 10 \text{ pF}$ for $\overline{\text{EMC_DYCSn}}$, $\overline{\text{EMC_RAS}}$, $\overline{\text{EMC_CAS}}$, $\overline{\text{EMC_WE}}$, $\overline{\text{EMC_An}}$; $C_L = 9 \text{ pF}$ for $\overline{\text{EMC_Dn}}$; $C_L = 5 \text{ pF}$ for $\overline{\text{EMC_DQMOUTn}}$, $\overline{\text{EMC_CLKn}}$, $\overline{\text{EMC_CKEOUTn}}$; $T_{amb} = -40^\circ\text{C}$ to $+105^\circ\text{C}$; $2.4 \text{ V} \leq V_{DD(\text{REG})}(3V_3) \leq 3.6 \text{ V}$; $V_{DD(\text{IO})} = 3.3 \text{ V} \pm 10\%$; $RD = 1$ (see *LPC18xx User manual*); $\overline{\text{EMC_CLKn}}$ delays $\text{CLK0_DELAY} = \text{CLK1_DELAY} = \text{CLK2_DELAY} = \text{CLK3_DELAY} = 0$.

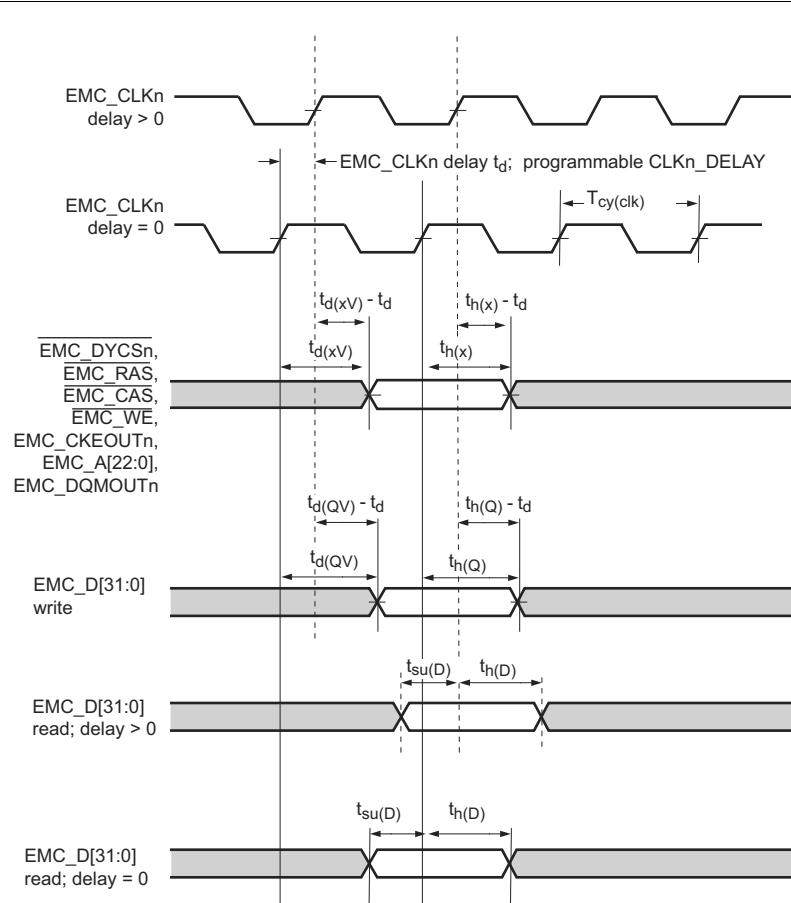
Symbol	Parameter	Min	Typ	Max	Unit
$T_{cy(\text{clk})}$	clock cycle time	8.4	-	-	ns
Common to read and write cycles					
$t_d(\text{DYCSV})$	dynamic chip select valid delay time	-	$3.1 + 0.5 \times T_{cy(\text{clk})}$	$5.1 + 0.5 \times T_{cy(\text{clk})}$	ns
$t_h(\text{DYCS})$	dynamic chip select hold time	$0.3 + 0.5 \times T_{cy(\text{clk})}$	$0.9 + 0.5 \times T_{cy(\text{clk})}$	-	ns
$t_d(\text{RASV})$	row address strobe valid delay time	-	$3.1 + 0.5 \times T_{cy(\text{clk})}$	$4.9 + 0.5 \times T_{cy(\text{clk})}$	ns
$t_h(\text{RAS})$	row address strobe hold time	$0.5 + 0.5 \times T_{cy(\text{clk})}$	$1.1 + 0.5 \times T_{cy(\text{clk})}$	-	ns
$t_d(\text{CASV})$	column address strobe valid delay time	-	$2.9 + 0.5 \times T_{cy(\text{clk})}$	$4.6 + 0.5 \times T_{cy(\text{clk})}$	ns
$t_h(\text{CAS})$	column address strobe hold time	$0.3 + 0.5 \times T_{cy(\text{clk})}$	$0.9 + 0.5 \times T_{cy(\text{clk})}$	-	ns
$t_d(\text{WEV})$	write enable valid delay time	-	$3.2 + 0.5 \times T_{cy(\text{clk})}$	$5.9 + 0.5 \times T_{cy(\text{clk})}$	ns
$t_h(\text{WE})$	write enable hold time	$1.3 + 0.5 \times T_{cy(\text{clk})}$	$1.4 + 0.5 \times T_{cy(\text{clk})}$	-	ns
$t_d(\text{DQMOUTV})$	DQMOUT valid delay time	-	$3.1 + 0.5 \times T_{cy(\text{clk})}$	$5.0 + 0.5 \times T_{cy(\text{clk})}$	ns
$t_h(\text{DQMOUT})$	DQMOUT hold time	$0.2 + 0.5 \times T_{cy(\text{clk})}$	$0.8 + 0.5 \times T_{cy(\text{clk})}$	-	ns
$t_d(\text{AV})$	address valid delay time	-	$3.8 + 0.5 \times T_{cy(\text{clk})}$	$6.3 + 0.5 \times T_{cy(\text{clk})}$	ns
$t_h(\text{A})$	address hold time	$0.3 + 0.5 \times T_{cy(\text{clk})}$	$0.9 + 0.5 \times T_{cy(\text{clk})}$	-	ns
$t_d(\text{CKEOUTV})$	CKEOUT valid delay time	-	$3.1 + 0.5 \times T_{cy(\text{clk})}$	$5.1 + 0.5 \times T_{cy(\text{clk})}$	ns
$t_h(\text{CKEOUT})$	CKEOUT hold time	$0.5 \times T_{cy(\text{clk})}$	$0.7 + 0.5 \times T_{cy(\text{clk})}$	-	ns
Read cycle parameters					
$t_{su(\text{D})}$	data input set-up time	-1.5	-0.5	-	ns
$t_h(\text{D})$	data input hold time	2.2	0.8	-	ns
Write cycle parameters					
$t_d(\text{QV})$	data output valid delay time	-	$3.8 + 0.5 \times T_{cy(\text{clk})}$	$6.2 + 0.5 \times T_{cy(\text{clk})}$	ns
$t_h(\text{Q})$	data output hold time	$0.5 \times T_{cy(\text{clk})}$	$0.7 + 0.5 \times T_{cy(\text{clk})}$	-	ns

Table 30. Dynamic characteristics: Dynamic external memory interface; EMC_CLK[3:0] delay values

$T_{amb} = -40^\circ\text{C}$ to 105°C ; $V_{DD(\text{IO})} = 3.3 \text{ V} \pm 10\%$; $2.4 \text{ V} \leq V_{DD(\text{REG})}(3V_3) \leq 3.6 \text{ V}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_d	delay time	delay value [1]	0.0	0.0	0.0	ns
		$\text{CLKn_DELAY} = 0$	0.0	0.0	0.0	ns
		$\text{CLKn_DELAY} = 1$	0.4	0.5	0.8	ns
		$\text{CLKn_DELAY} = 2$	0.7	1.0	1.7	ns
		$\text{CLKn_DELAY} = 3$	1.1	1.6	2.5	ns
		$\text{CLKn_DELAY} = 4$	1.4	2.0	3.3	ns
		$\text{CLKn_DELAY} = 5$	1.7	2.6	4.1	ns
		$\text{CLKn_DELAY} = 6$	2.1	3.1	4.9	ns
		$\text{CLKn_DELAY} = 7$	2.5	3.6	5.8	ns

- [1] Program the $\overline{\text{EMC_CLKn}}$ delay values in the $\overline{\text{EMCDELAYCLK}}$ register (see the *LPC18xx User manual*). The delay values must be the same for all SDRAM clocks $\overline{\text{EMC_CLKn}}$: $\text{CLK0_DELAY} = \text{CLK1_DELAY} = \text{CLK2_DELAY} = \text{CLK3_DELAY} = 0$.



002aag703

For the programmable EMC_CLK[3:0] clock delays CLKn_DELAY, see [Table 30](#).

Remark: For SDRAM operation, set CLK0_DELAY = CLK1_DELAY = CLK2_DELAY = CLK3_DELAY in the EMCDELAYCLK register.

Fig 34. SDRAM timing

11.14 USB interface

Table 31. Dynamic characteristics: USB0 and USB1 pins (full-speed)

$C_L = 50 \text{ pF}$; $R_{pu} = 1.5 \text{ k}\Omega$ on D+ to $V_{DD(\text{IO})}$, unless otherwise specified; $3.0 \text{ V} \leq V_{DD(\text{IO})} \leq 3.6 \text{ V}$.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
t_r	rise time	10 % to 90 %	4.0	-	20.0	ns
t_f	fall time	10 % to 90 %	4.0	-	20.0	ns
t_{FRFM}	differential rise and fall time matching	t_r / t_f	90	-	111.11	%
V_{CRS}	output signal crossover voltage		1.3	-	2.0	V
t_{FEOPT}	source SE0 interval of EOP	see Figure 35	160	-	175	ns
t_{FDEOP}	source jitter for differential transition to SE0 transition	see Figure 35	-2	-	+5	ns
t_{JR1}	receiver jitter to next transition		-18.5	-	+18.5	ns
t_{JR2}	receiver jitter for paired transitions	10 % to 90 %	-9	-	+9	ns
t_{EOPR1}	EOP width at receiver	must reject as EOP; see Figure 35	[1]	40	-	ns
t_{EOPR2}	EOP width at receiver	must accept as EOP; see Figure 35	[1]	82	-	ns

[1] Characterized but not implemented as production test. Guaranteed by design.

Remark: If only USB0 (HS USB) is used, the pins VDDREG and VDDIO can be at different voltages within the operating range but should have the same ramp up time. If USB1(FS USB) is used, the pins VDDREG and VDDIO should be a minimum of 3.0 V and be tied together.

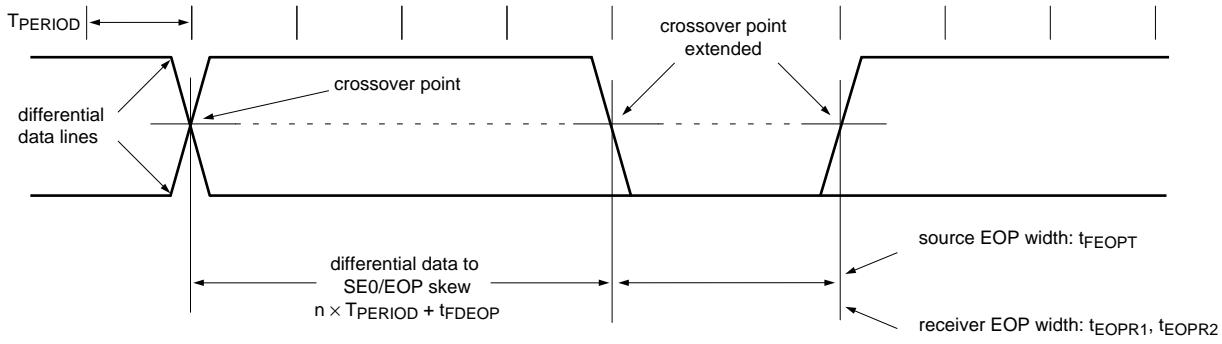


Fig. 35. Differential data-to-EOP transition skew and EOP width

12. ADC/DAC electrical characteristics

Table 37. ADC characteristics

$V_{DDA(3V3)}$ over specified ranges; $T_{amb} = -40^{\circ}\text{C}$ to $+105^{\circ}\text{C}$; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{IA}	analog input voltage		0	-	$V_{DDA(3V3)}$	V
C_{ia}	analog input capacitance		-	-	2	pF
E_D	differential linearity error	$2.7 \text{ V} \leq V_{DDA(3V3)} \leq 3.6 \text{ V}$	[1][2]	-	± 0.8	-
		$2.4 \text{ V} \leq V_{DDA(3V3)} < 2.7 \text{ V}$		-	± 1.0	LSB
$E_{L(adj)}$	integral non-linearity	$2.7 \text{ V} \leq V_{DDA(3V3)} \leq 3.6 \text{ V}$	[3]	-	± 0.8	LSB
		$2.4 \text{ V} \leq V_{DDA(3V3)} < 2.7 \text{ V}$		-	± 1.5	LSB
E_O	offset error	$2.7 \text{ V} \leq V_{DDA(3V3)} \leq 3.6 \text{ V}$	[4]	-	± 0.15	LSB
		$2.4 \text{ V} \leq V_{DDA(3V3)} < 2.7 \text{ V}$		-	± 0.15	LSB
E_G	gain error	$2.7 \text{ V} \leq V_{DDA(3V3)} \leq 3.6 \text{ V}$	[5]	-	± 0.3	-
		$2.4 \text{ V} \leq V_{DDA(3V3)} < 2.7 \text{ V}$		-	± 0.35	%
E_T	absolute error	$2.7 \text{ V} \leq V_{DDA(3V3)} \leq 3.6 \text{ V}$	[6]	-	± 3	LSB
		$2.4 \text{ V} \leq V_{DDA(3V3)} < 2.7 \text{ V}$		-	± 4	LSB
R_{vsi}	voltage source interface resistance	see Figure 40	-	-	$1/(7 \times f_{clk(ADC)} \times C_{ia})$	kΩ
R_i	input resistance		[7][8]	-	1.2	MΩ
$f_{clk(ADC)}$	ADC clock frequency		-	-	4.5	MHz
f_s	sampling frequency	10-bit resolution; 11 clock cycles	-	-	400	kSamples/s
		2-bit resolution; 3 clock cycles			1.5	MSamples/s

- [1] The ADC is monotonic, there are no missing codes.
- [2] The differential linearity error (E_D) is the difference between the actual step width and the ideal step width. See [Figure 39](#).
- [3] The integral non-linearity ($E_{L(adj)}$) is the peak difference between the center of the steps of the actual and the ideal transfer curve after appropriate adjustment of gain and offset errors. See [Figure 39](#).
- [4] The offset error (E_O) is the absolute difference between the straight line which fits the actual curve and the straight line which fits the ideal curve. See [Figure 39](#).
- [5] The gain error (E_G) is the relative difference in percent between the straight line fitting the actual transfer curve after removing offset error, and the straight line which fits the ideal transfer curve. See [Figure 39](#).
- [6] The absolute error (E_T) is the maximum difference between the center of the steps of the actual transfer curve of the non-calibrated ADC and the ideal transfer curve. See [Figure 39](#).
- [7] $T_{amb} = 25^{\circ}\text{C}$.
- [8] Input resistance R_i depends on the sampling frequency f_s : $R_i = 2 \text{ k}\Omega + 1 / (f_s \times C_{ia})$.

14. Package outline

LBGA256: plastic low profile ball grid array package; 256 balls; body 17 x 17 x 1 mm

SOT740-2

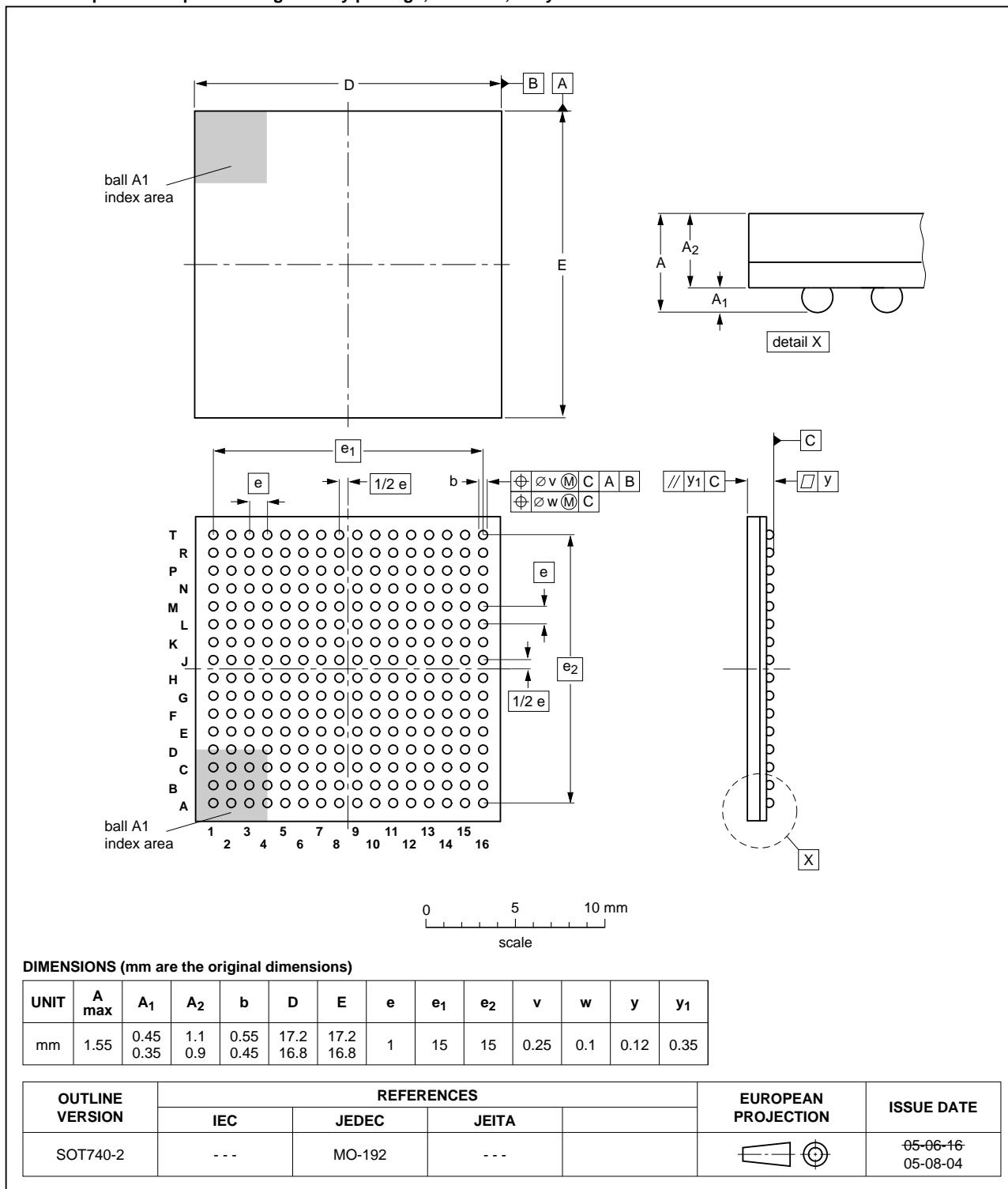


Fig 49. Package outline of the LBGA256 package

LQFP144: plastic low profile quad flat package; 144 leads; body 20 x 20 x 1.4 mm

SOT486-1

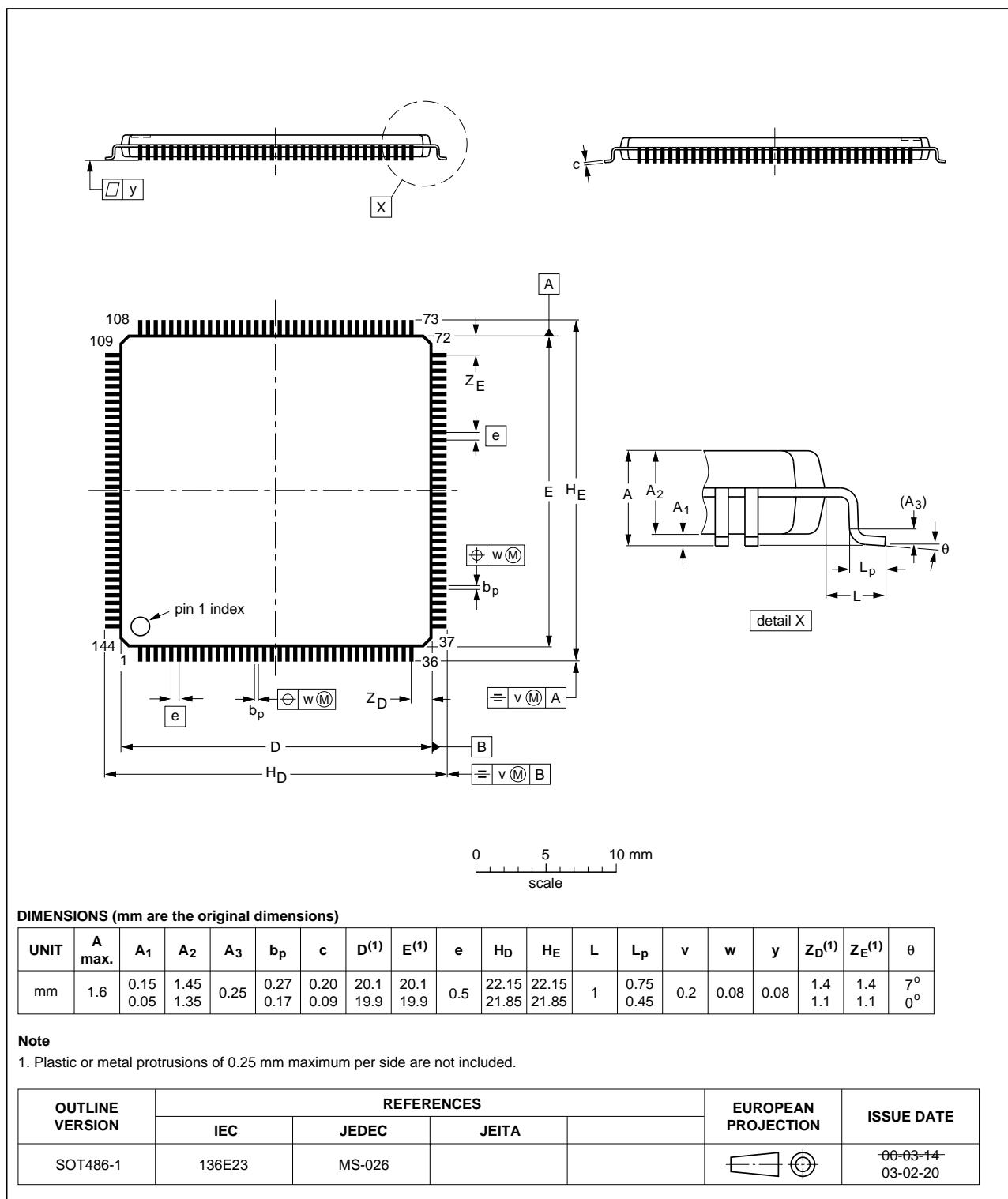


Fig 52. Package outline of the LQFP100 package

18. Revision history

Table 45. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
LPC185X_3X_2X_1X v.5.2	20160308	Product data sheet	-	LPC185X_3X_2X_1X v.5.1
Modifications:	<ul style="list-style-type: none"> Updated Table 29 "Dynamic characteristics: Dynamic external memory interface": Read cycle parameters $t_{H(D)}$ min value is 2.2 ns and max value is "-". 			
LPC185X_3X_2X_1X v.5.1	20151117	Product data sheet	2015110041	LPC185X_3X_2X_1X v.5
Modifications:	<ul style="list-style-type: none"> Updated Table 2 "Ordering options"; TFBGA100 packages do not support ULPI interface. Updated SSP slave and SSP master values in Table 27 "Dynamic characteristics: SSP pins in SPI mode". Updated footnote 2 to: $T_{cy(clk)} \geq 12 \times T_{cy(PCLK)}$. <ul style="list-style-type: none"> removed $t_{V(Q)}$, data output valid time in SPI mode, minimum value of 3 \cdot (1/PCLK) from SSP slave mode. added units to t_d, delay time, for SSP slave and master mode. Added GPCLKIN section and table. See Section 11.7 "GPCLKIN" and Table 22 "Dynamic characteristic: GPCLKIN". 			
LPC185X_3X_2X_1X v.5	20150429	Product data sheet	-	LPC185X_3X_2X_1X v.4.1

Table 45. Revision history ...continued

Document ID	Release date	Data sheet status	Change notice	Supersedes
LPC1857_53 v.3.1	20120904	Preliminary data sheet	-	LPC1857_53 v.3
Modifications:		<ul style="list-style-type: none"> • SSP0 boot pin functions added in Table 5 and Table 4. Pin P3_3 = SSP0_SCK, pin P3_6 = SSP0_SSEL, pin P3_7 = SSP0_MISO, pin P3_8 = SSP0_MOSI. • Peripheral power consumption data added in Table 12. • BOD de-assertion levels add in Table 13. • Minimum value for all supply voltages changed to -0.5 V n Table 7. 		
LPC1857_53 v.3	20120711	Preliminary data sheet	-	LPC1857_53 v.2
Modifications:		<ul style="list-style-type: none"> • Data sheet status changed to preliminary. • AES removed. Available on parts LPC18Sxx only. • Minimum value of V_I for conditions "USB0 pins USB0_DP; USB0_DM; USB0_VBUS", "USB0 pins USB0_ID; USB0_RREF", and "USB1 pins USB1_DP and USB1_DM" changed to -0.3 V in Table 6. • Dynamic characteristics of the SD/MMC controller updated in Table 29. • Dynamic characteristics of the LCD controller updated in Table 30. • Dynamic characteristics of the SSP controller updated in Table 22. • Section 10.2 added. • Table 8 "Thermal resistance value (BGA packages)" added. • Description of pins USB1_DP and USB1_DM updated in Table 3. • Editorial updates. • Parameters I_{IL} and I_{IH} renamed to I_{LL} and I_{LH} in Table 9. 		
LPC1857_53 v.2	20120515	Objective data sheet	-	LPC1857_53 v.1
LPC1857_53 v.1	20111214	Objective data sheet	-	-